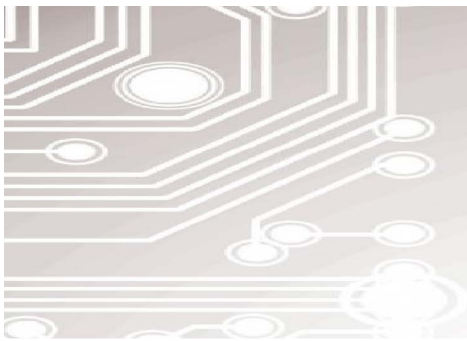


Polyimide Laminate and Prepreg



85N is the ultimate pure polyimide laminate and prepreg system. Bromine-free chemistry provides Best-in-Class thermal stability for applications with sustained high in-use temperatures as well as for use in lead-free soldering applications.

Features:

- Meets IPC4101/40 and /41 description and specification
 - Pure polyimide, no secondary resin
 - No epoxy added, blended or reacted
- Best-in-Class thermal properties
 - T_g => 250°C
 - Decomposition temperature >407°C
 - T₃₀₀ > 60 min.
- Low Z-axis expansion
 - 1.2% between 50-260°C (vs. 2.5-4.0% for typical high-performance epoxies)
 - Minimizes the risk of latent PTH defects caused during solder reflow and device attachment.
- Decomposition temperature of 407°C, compared with 300-360°C for typical high-performance epoxies, offering outstanding long-term high-temperature performance
- Toughened chemistry resists resin fracturing
- Halogen-free chemistry
- Compatible with lead-free processing
- RoHS/WEEE compliant

Typical Applications:

- PCB's that are subjected to high temperatures during processing, such as lead-free soldering, HASL, IR Reflow
 - Applications with long term exposure to high temperatures such as aircraft engine instrumentation, down hole drilling, under-hood automotive controls, burn-in boards, or industrial sensors
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Typical Properties:

Property	Units	Value	Test Method
Electrical Properties			
Dielectric Constant @ 1 MHz	-	4.2	IPC TM-650 2.5.5.3
@ 1 GHz	-	4.0	
Dissipation Factor @ 1 MHz		0.01	IPC TM-650 2.5.5.3
@ 1 GHz		N/A	
Volume Resistivity			
C96/35/90	MΩ-cm	1.5×10^8	IPC TM-650 2.5.17.1
E24/125	MΩ-cm	3.0×10^{10}	IPC TM-650 2.5.17.1
Surface Resistivity			
C96/35/90	MΩ	1.6×10^9	IPC TM-650 2.5.17.1
E24/125	MΩ	1.6×10^9	IPC TM-650 2.5.17.1
Electrical Strength	Volts/mil (kV/mm)	1450 (57.1)	IPC TM-650 2.5.6.2
Dielectric Breakdown	kV	>40	IPC TM-650 2.5.6
Arc Resistance	sec	143	IPC TM-650 2.5.1
Thermal Properties			
Glass Transition Temperature (Tg)			
TMA	°C	=>250	IPC TM-650 2.4.24
Decomposition Temperature			
Initial	°C	387	IPC TM-650 2.4.24.6
5% weight loss	°C	407	IPC TM-650 2.4.24.6
T260	min	>60	IPC TM-650 2.4.24.1
T288	min	>60	IPC TM-650 2.4.24.1
T300	min	>60	IPC TM-650 2.4.24.1
CTE (X,Y)	ppm/°C	16	IPC TM-650 2.4.41
CTE (Z)			
< Tg	ppm/°C	55	IPC TM-650 2.4.24
> Tg	ppm/°C	149	IPC TM-650 2.4.24
z-axis Expansion (50-260°C)	%	1.2	IPC TM-650 2.4.24
Mechanical Properties			
Peel Strength to Copper (1 oz/35 micron)			
After Thermal Stress	lb./in (N/mm)	6.4 (1.1)	IPC TM-650 2.4.8
At Elevated Temperatures	lb./in (N/mm)	6.4 (1.1)	IPC TM-650 2.4.8.2
After Process Solutions	lb./in (N/mm)	6.4 (1.1)	IPC TM-650 2.4.8
Young's Modulus CD/MD	Mpsi (GPa)	3.6/4.1 (24.8/28.2)	ASTM E111
Tensile Strength CD/MD	kpsi (MPa)	48/64 (330/440)	ASTM D3039
Poisson's Ratio	-	0.18	ASTM E13204
Physical Properties			
Water Absorption (0.062")	%	0.27	IPC TM-650 2.6.2.1
Density	g/cm ³	1.6	ASTM D792 Method A
Thermal Conductivity	W/mK	0.2	ASTM E1461
Flammability	class	HB	UL-94

Results listed above are typical properties, provided without warranty, expressed or implied, and without liability. Properties may vary, depending on design and application. Arlon reserves the right to change or update these values.

Availability:

Arlon Part Number	Glass Style	Resin (%)	Scaled Flow Hf (mils)	Scaled Flow Δ H (mils)
85N0672	106	72	1.7 ± 0.3	0.75 ± 0.20
85N8063	1080	63	2.4 ± 0.3	0.75 ± 0.20
85N2355	2313	55	3.4 ± 0.3	0.75 ± 0.20
85N2650	2116	50	4.1 ± 0.3	0.75 ± 0.20
85N2840	7628	40	6.6 ± 0.3	0.70 ± 0.20

Recommended Process Conditions:

Process inner-layers through develop, etch, and strip using standard industry practices. Use brown oxide on inner layers. Adjust dwell time in the oxide bath to ensure uniform coating. Bake inner layers in a rack for 60 minutes at 107°C - 121°C (225°F - 250°F) immediately prior to lay-up. Store prepreg at 60-70°F at or below 30% RH. Vacuum desiccate the prepreg for 8 - 12 hours prior to lamination.

Lamination Cycle:

- 1) Pre-vacuum for 30 - 45 minutes
- 2) Control the heat rise to 4.5°C - 6.5°C (8°F - 12°F) per minute between 100°C and 150°C (210°F and 300°F). Vacuum lamination is preferred. Start point vacuum lamination pressures are shown in the table below:

Panel Size		Pressure	
in.	mm	psi	kg/cm ²
12 x 18	305 x 457	230	16
16 x 18	406 x 457	300	21
18 x 24	457 x 610	325	23

- 3) Set cure temperature at 218°C (425°F). Start cure time when product temperature > 213°C (415°F)
- 4) Cure time at temperature = 120 minutes
- 5) Cool down under pressure at ≤ 5°C/min (10°F/min)

Drill at 350 SFM. Undercut bits are recommended for vias 0.018" (0.45mm) and smaller
De-smear using alkaline permanganate or plasma with settings appropriate for polyimide;
plasma is preferred for positive etchback

Conventional plating processes are compatible with 85N

Standard profiling parameters may be used; chip breaker style router bits are not recommended
Bake for 1 - 2 hours at 250°F (121°C) prior to solder to reflow of HASL

... Challenge Us!

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